

20A Standard SCRs

Product Summary

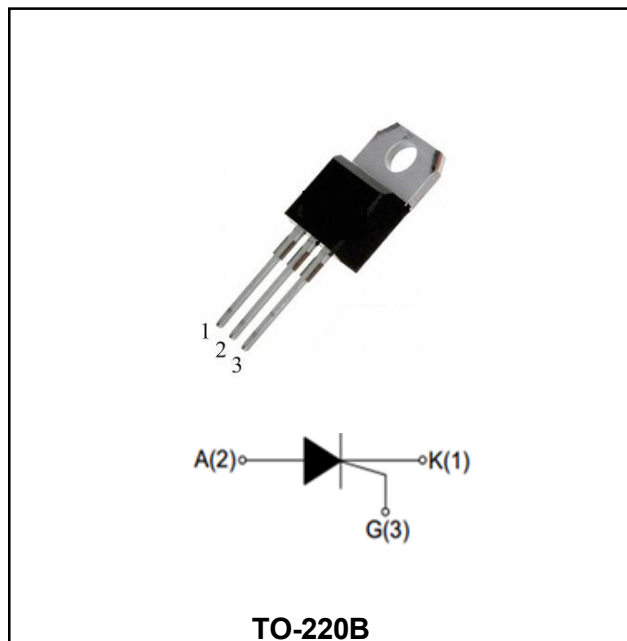
Symbol	Value	Unit
$I_{T(RMS)}$	20	A
$V_{DRM} V_{RRM}$	600/800	V
V_{TM}	1.6	V

Features

With high ability to withstand the shock loading of large current, Provide high dv/dt rate with strong resistance to electromagnetic interference.

Application

Power charger, T-tools, massager, solid state relay, AC Motor speed regulation and so on.



Order Information

Part Number	Package	Marking	packing	Delivery Quantity
BT152	TO-220B	BT152-600 XXXX	BOX	1000PCS/BOX
BT152	TO-220B	BT152-800 XXXX	BOX	1000PCS/BOX

Absolute maximum ratings (Ta=25°C unless otherwise noted)

Parameter	Symbol	Value	Unit
Repetitive peak off-state voltage	V_{DRM}	600/800	V
Repetitive peak reverse voltage	V_{RRM}	600/800	V
RMS on-state current	$I_{T(RMS)}$	20	A
Non repetitive surge peak on-state current	I_{TSM}	200	A
I^2t value for fusing (tp=10ms)	I^2t	200	A ² s
Critical rate of rise of on-state current ($I_G = 2 \times I_{GT}$)	di/dt	I - II - III 50	A/ μ s
Peak gate current	I_{GM}	5	A
Average gate power dissipation	$P_G (AV)$	1	W
Junction Temperature	T_J	-40~+125	°C
Storage Temperature	T_{STG}	-40 ~+150	°C

Electrical characteristics (TA=25°C, unless otherwise noted)

Parameter	Symbol	Test Condition	Value			Unit
			min	typ	max	
Gate trigger current	I_{GT}	$V_D=12V, I_T=0.1A, T_j=25^\circ C, \text{Fig. 6}$	-	-	30	mA
Gate trigger voltage	V_{GT}	$V_D=12V, I_T=0.1A, T_j=25^\circ C$	-	0.7	1.0	V
Non-triggering gate voltage	V_{GD}	$V_D=V_{DRM}, T_j=125^\circ C$	0.2	-	-	V
Holding current	I_H	$V_D=12V, I_{GT}=0.1A, T_j=25^\circ C, \text{Fig. 6}$	-	-	50	mA
Latching current	I_L		-	-	60	mA
Critical-rate of rise of commutation voltage	dV_D/dt	$V_D=67\%V_{DRM}, T_j=125^\circ C$	200	-	-	V/μs

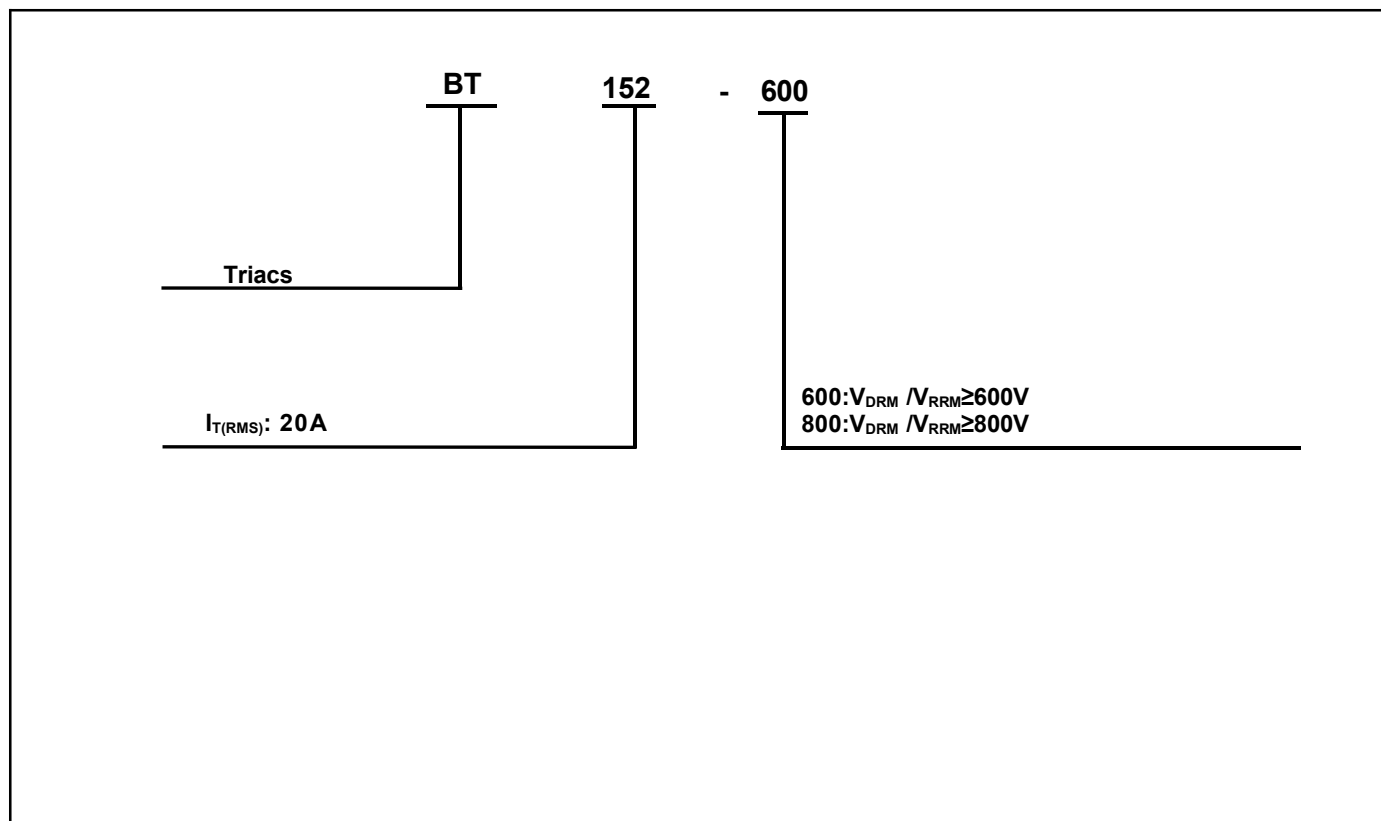
STATIC CHARACTERISTICS

On-state Voltage	V_{TM}	I _{TM} =32A, tp=380μs, T _j =25°C ,Fig. 4		-	-	1.6	V
Repetitive Peak Off-State Current	I_{DRM}	V _D =V _{DRM} = V _{RRM}	T _j =25°C	-	-	10	μA
Repetitive Peak Reverse Current	I_{RRM}		T _j =125°C	-	-	1	mA

THERMAL RESISTANCES

Thermal resistance	$R_{th(j-c)}$	Junction to case	TYP.	1.05	$^\circ C/W$
	$R_{th(j-a)}$	Junction to ambient	TYP.	60	$^\circ C/W$

Ordering Information



Typical Characteristics

FIG.1: Maximum power dissipation versus RMS on-state current (full cycle)

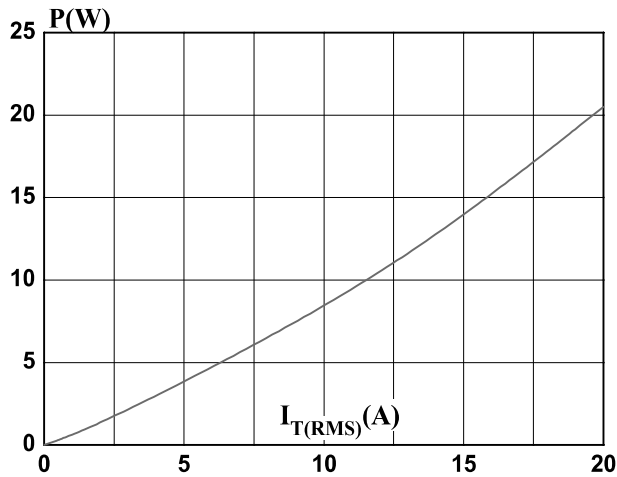


FIG.2: RMS on-state current versus case temperature (full cycle)

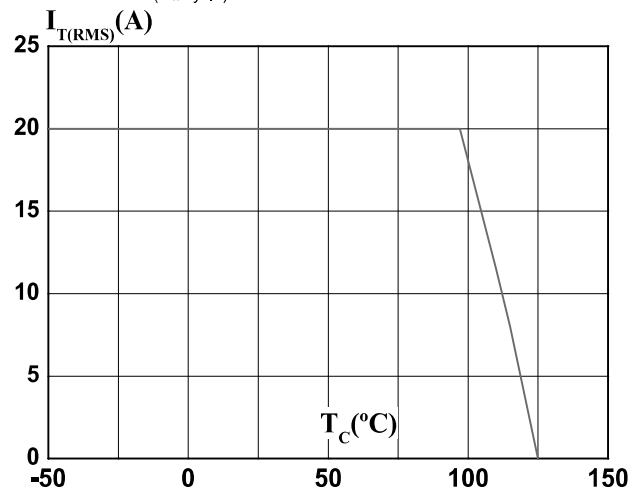


FIG.3: Surge peak on-state current versus number of cycles

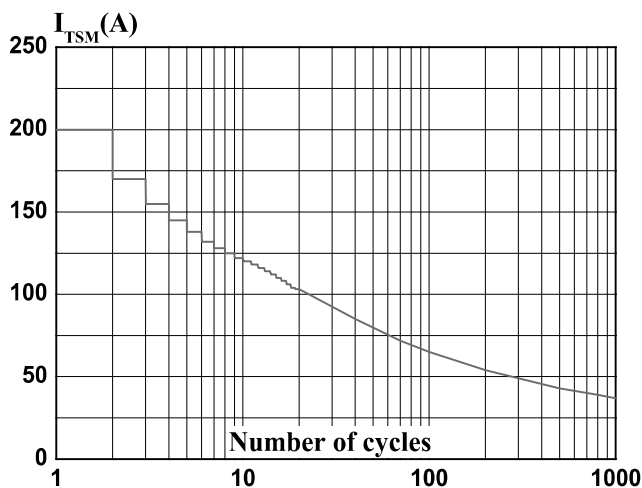


FIG.4: On-state characteristics (maximum values)

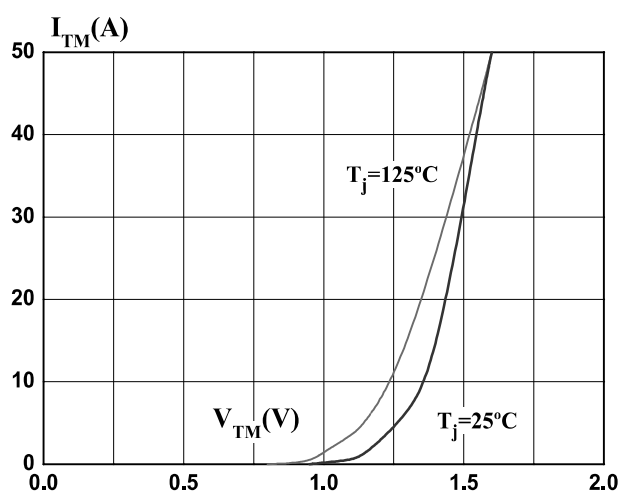


FIG.5: Non-repetitive surge peak on-state current for a sinusoidal pulse with width $t_p < 10ms$

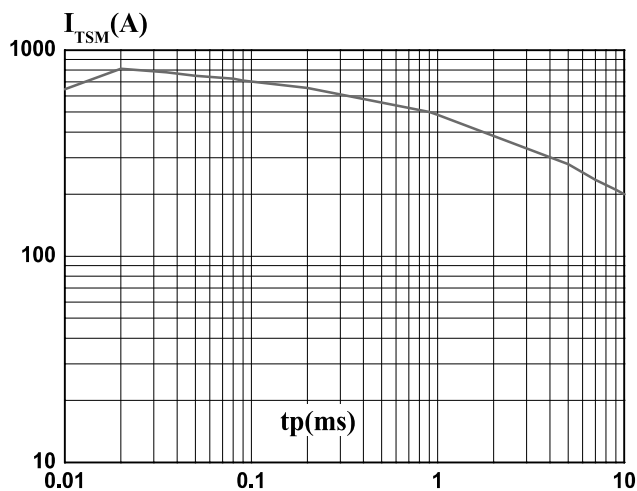
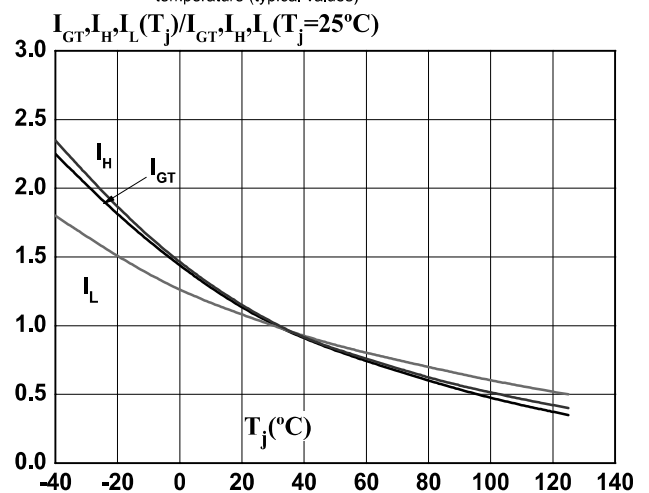
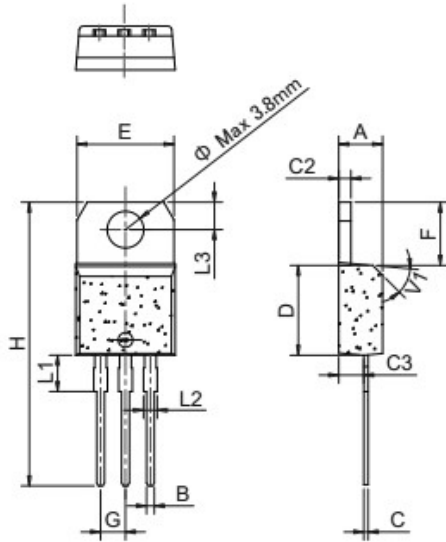


FIG.6: Relative variations of gate trigger current, holding current and latching current versus junction temperature (typical values)



Package Information

TO-220B



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	4.40		4.60	0.173		0.181
B	0.61		0.88	0.024		0.035
C	0.46		0.70	0.018		0.028
C2	1.21		1.32	0.048		0.052
C3	2.40		2.72	0.094		0.107
D	8.60		9.70	0.339		0.382
E	9.60		10.4	0.378		0.409
F	6.20		6.60	0.244		0.260
G		2.54			0.1	
H	28.0		29.8	1.102		1.173
L1		3.75			0.148	
L2	1.14		1.70	0.045		0.067
L3	2.65		2.95	0.104		0.116
V1		45°			45°	